

Optical Pumping of the Electronic and Nuclear Spin of Single Charge-Tunable Quantum Dots

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We present a comprehensive examination of optical pumping of spins in individual GaAs quantum dots as we change the net charge from positive to neutral to negative with a charge-tunable heterostructure. Negative photoluminescence polarization memory is enhanced by optical pumping of ground state electron spins, which we prove with the first measurements of the Hanle effect on an individual quantum dot. We use the Overhauser effect in a high longitudinal magnetic field to demonstrate efficient optical pumping of nuclear spins for all three charge states of the quantum dot.

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Remarkable advances in the optical spectroscopy of semiconductor spins [1] may someday provide the means to harness spin in nanostructures for quantum information processing. One promising approach is to address individual carrier spins in semiconductor quantum dots (QDs) and to manipulate them through optically excited states (charged excitons) [2–6]. With this approach, qubit initialization and readout of an electron spin can be achieved with the classic techniques of optical orientation [1].

Here, we use optical orientation to pump and probe the spin state of carriers and nuclei in an individual semiconductor quantum dot, taking an important step toward initialization and readout. Optical orientation begins with the conversion of circularly polarized light into a spin-polarized electron-hole pair. Through spin relaxation, this polarization may transfer to other spin degrees of freedom such as ground state electron or nuclear spins. These optically pumped spin polarizations can persist long after excitonic recombination is over, providing the type of “spin memory” that is needed for storage and processing of information.

Although the techniques of optical orientation have been widely applied to semiconductor bulk and quantum well systems [1], there are few reports of such work in QDs. These include direct measurements of excitonic polarization in charged QD ensembles [7–12] and single QDs [13], and demonstrations of optical pumping of electrons [7,8] and nuclei [14]. In this work, we use measurements of luminescence polarization, the Hanle effect, and the Overhauser effect to demonstrate optical pumping of excitonic, electron, and nuclear spins within a single charge-tunable QD. This approach reveals a level of detail that has not been achieved previously in measurements on an ensemble or on a single nanostructure.

The QDs that we investigate are defined by monolayer-high steps at the interfaces of a 4 nm GaAs/AlGaAs quantum well [15]. The quantum well layer is contained within a Schottky diode heterostructure that provides con-

trol of charge injection with an applied bias [16]. Samples were excited with circularly polarized light from a Ti:sapphire laser tuned into the quasicontinuum above the lateral QD potential barrier. The photoluminescence (PL) polarization (or “polarization memory”) [1,7] is $\rho = (I_+ - I_-)/(I_+ + I_-)$, where I_+ (I_-) is the PL intensity measured after passing through a right (left) circular polarization analyzer. The light is then dispersed in a spectrometer and detected with a multichannel charge coupled device except for the measurement of the Hanle effect, where a photon counting avalanche photodiode was phase locked to a 40 kHz polarization modulation of the exciting light to prevent nuclear polarization.

Positive circularly polarized laser light (σ^+) at normal incidence produces spin “up” holes $h(\uparrow)$, with total angular momentum projection $m_h = +3/2$ along the growth direction, and spin “down” electrons $e(\downarrow)$, with $m_e = -1/2$. An electron-hole pair, or exciton, is captured into the charged or neutral QD and recombines there, emitting characteristic polarized PL. The charged excitons X^+ and X^- (often called trions because they consist of three particles) are shown schematically in Fig. 1(c), together with the neutral exciton X^0 . The lowest energy negative (positive) trion consists of two paired electrons (holes) in a singlet configuration and an unpaired hole (electron). The PL polarization of X^- is determined by the spin of the hole, while that of X^+ is determined by the electron.

The trion states of an individual QD are clearly identified by the energy of the emitted photon [15–23], which is shifted relative to the emission from a neutral exciton. The PL spectrum in Fig. 1(a) shows the positive trion (X^+), neutral exciton (X^0), and negative trion (X^-) over a range of biases. The PL polarization changes sign when the QD charge changes sign, even though the σ^+ -polarized laser always excites $e(\downarrow)$ - $h(\uparrow)$ pairs. Around 4 V bias, the polarization [Fig. 1(b)] is positive for X^+ , roughly zero for X^0 , and negative [7,8,10] for X^- . The X^- shows the richest behavior. At the highest laser intensity (open circles), the

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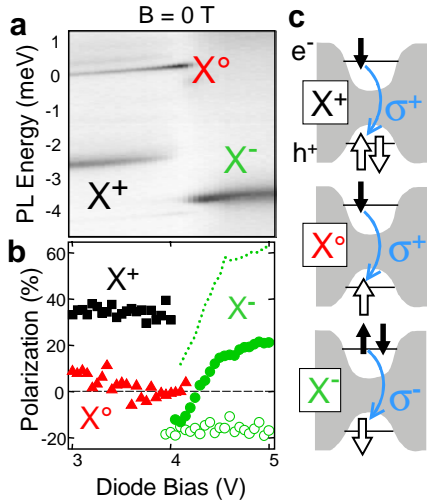


FIG. 1 (color online). (a) PL intensity (gray scale) for the neutral exciton (X^0), negative trion (X^-), and positive trion (X^+) in a single QD as a function of emitted photon energy and applied bias. The PL energy scale is relative to the X^0 peak at 3 V bias ($E_{X^0} = 1.663$ eV). The excitation photon energy was 1.691 eV ($E_{X^0} + 28$ meV). (b) PL polarization memory for spectra in (a) (solid symbols). Open circles: 15 times higher excitation intensity. Dotted line: excitation energy $E_{X^0} + 15$ meV. (c) QD band profiles with spin configurations.

X^- polarization is negative for all values of the bias. At lower laser intensity (solid circles), the polarization is negative only near the charging threshold, but changes to positive with applied bias as unpolarized electrons are injected. Finally, for lower laser excitation energy (15 meV above the neutral exciton line instead of 28 meV above), the X^- polarization is positive for all biases (dotted line).

Negative polarization of X^- implies that the heavy-hole spin has flipped prior to recombination, while positive polarization of X^+ implies that the electron spin has not flipped. The heavy-hole spin flip time is much shorter than that of the electron due to spin-orbit interaction in the valence band states. This is a well-established behavior of 2D charge carriers with excess energy (hot carriers) [24]. In addition, however, negative polarization of X^- actually implies that a spin-flipped hole $h(\downarrow)$ contributes to X^- formation with higher probability than a nonflipped hole $h(\uparrow)$. Previous work [7] has indeed shown that non-radiative dark excitons $X^0(\downarrow\downarrow)$ can play the role of accumulating spin-flipped holes if the electrons also remain highly polarized. This happens because photogenerated bright excitons $X^0(\uparrow\uparrow)$ recombine radiatively within a short time, while dark excitons $X^0(\downarrow\downarrow)$ arising from a hot-hole spin flip survive much longer and have a greater chance of being trapped in a charged QD, where they can form a trion. The magnitude and the sign of X^- polarization depend on the relative probability for a charged QD to capture a bright or dark exciton. When dark excitons $X^0(\downarrow\downarrow)$

dominate, the PL polarization is negative. For example, lower excitation energy inhibits the hole spin flip that produces dark excitons in the first place, and we observe that the X^- polarization becomes more positive [Fig. 1(b) (dotted line)]. Negative polarization is most pronounced at high laser intensities (open circles) or near the X^- formation threshold bias (~ 4 V), where the electrons are strongly polarized by the laser. When the bias is increased (solid circles and dotted line), the X^- polarization becomes more positive due to electrical injection of unpolarized electrons, which overwhelm the influence of the photoelectrons.

Notably, the capture of a dark exciton $X^0(\downarrow\downarrow)$ by the QD changes the spin state of the QD electron: The formation of singlet $X^- (\uparrow\downarrow)$ requires the presence of a QD electron $e(\uparrow)$, but after X^- recombination, the spin down electron $e(\downarrow)$ is left. This corresponds, in the language of atomic physics, to *optical pumping* of the ground state electron spin.

With the Hanle effect, we directly measure optical pumping of the electron spin. A small transverse magnetic field (B_x , in the QD plane) erases the contribution of the oriented electron to the PL polarization [1,7,11]. Paired carriers are not affected by the magnetic field because their net spin is zero, and unpaired holes are not affected because their g factor is nearly zero in the plane of the QD [15]. Depolarization of luminescence occurs when B_x is large enough to make the electron spin precess faster than the rate of intrinsic dephasing and recombination. In the simplest case, the depolarization curve is Lorentzian with half-width $B_{1/2} = \hbar/T_s g_e \mu_B$, where T_s is the electron spin lifetime, g_e is its g factor (~ 0.2) and μ_B is the Bohr magneton ($59 \mu\text{eV/T}$).

There is a marked difference between the Hanle line-widths for X^- and X^+ in a single QD [Fig. 2(a)]. For X^+ , an unpaired electron is present in the trion itself, and its lifetime is limited by fast radiative recombination. The broad Hanle feature (3.5 kG half-width) corresponds to a lifetime of 150 ps, roughly consistent with the expected radiative recombination time for these large GaAs QDs [25]. In contrast, a typical Hanle peak for X^- is very sharp. At low laser powers, we measure a half-width of 35 G, corresponding to a lifetime of 16 ns. This lifetime is too long to be associated with recombination and indicates that the Hanle effect depolarizes the unpaired ground state electron, which influences subsequent X^- formation [26]. The X^- itself does not respond to the transverse field because it has no unpaired electrons.

The lifetime obtained from the X^- Hanle effect can be compared to what we expect for a localized electron influenced by fluctuations in the local nuclear spin environment [27,28]. The nuclear spins are static during an optical cycle but fluctuate during the long measurement time. The fluctuating spins, via the hyperfine interaction, behave like an effective magnetic field and lead to spectral diffusion that broadens the Hanle curve. The dephasing time for this

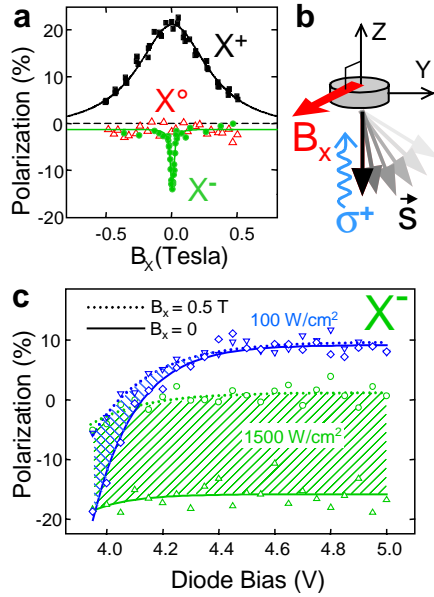


FIG. 2 (color online). (a) Hanle effect measurements for all three charge states. (b) Experimental geometry: optically created spins (antiparallel to Z) precess in the Y - Z plane about the magnetic field B_x . (c) Bias dependence of X^- polarization for two laser intensities and two magnetic fields. The thickness of the shaded regions corresponds to the depth of the X^- Hanle peak.

process is $T \approx \hbar\sqrt{N}/A$, where $A = 90 \mu\text{eV}$ is the hyperfine constant in GaAs and N is the number of nuclear spins within the wave function of the QD electron [27]. The measured spin lifetime of 16 ns corresponds to 5×10^6 nuclei or a diameter of 170 nm (for 4 nm thickness). This is somewhat larger than a typical natural GaAs QD but within the expected size range. A more complete interpretation of the linewidth will require further study.

We pump the electron spin most efficiently when the laser intensity is high. The depth of the Hanle peak for X^- is proportional to the degree of ground state electron polarization. We have measured X^- polarization with and without a transverse magnetic field in order to see how the peak depth depends on bias and intensity. This is depicted in Fig. 2(c) by the thickness of the shaded regions for two laser intensities. While the shaded region represents the influence of the electron spin on PL polarization, the upper dotted curves ($B_x = 0.5$ T) represent the remaining contribution that comes purely from holes [26]. At the higher laser intensity, polarized photogenerated electrons replace electrically injected electrons, so the Hanle peak depth is relatively large (roughly 15%) for all biases. In contrast, for lower laser intensity the Hanle peak is only large near the charging threshold at 4 V but disappears as the bias is increased. This change coincides with the increase in trion PL polarization and results from electrical injection of unpolarized electrons. These results show the

clear correlation between the sign of X^- polarization and the degree of electron spin pumping (Hanle peak depth).

Measurements in a high longitudinal magnetic field complete the picture of optical orientation in single QDs. Each of the PL peaks splits into a Zeeman doublet [Figs. 3(a) and 4(a)], and we measure doublet splittings and intensities obtained with both laser polarizations. A raw polarization $\rho_{\text{raw}} = (I_+ - I_-)/(I_+ + I_-)$ is obtained directly from the intensities I_+ and I_- of the two peaks in the Zeeman doublet. ρ_{raw} is shown in Fig. 3(b) as a function of the laser polarization, which is controlled by a variable retarder. The polarization memory is calculated using $\rho = (\rho_{\text{raw}}^+ - \rho_{\text{raw}}^-)/2$, where ρ_{raw}^\pm are the raw polarizations obtained with the corresponding laser helicity σ^\pm . This removes the part of the raw polarization arising from thermalization between Zeeman levels. The amplitude of the curves in Fig. 3(b) corresponds to the polarization memory.

The high magnetic field restores the positive circular polarization of the neutral exciton ($\approx 40\%$), which is otherwise suppressed by the anisotropic electron-hole exchange interaction in an asymmetric QD [29]. The 5 T magnetic field changes the X^+ and X^- polarizations very little [Fig. 4(b)]. We note, in particular, that the negative polarization of X^- persists. This is important because it implies that an alternative mechanism for negative polarization that involves exchange interactions in triplet states [8] is less important here. Such a mechanism should show a dependence on magnetic field.

Finally, we demonstrate efficient optical pumping of the nuclear spins in all three charge states of the QD at 5 T. When electrons are optically oriented, they can transfer

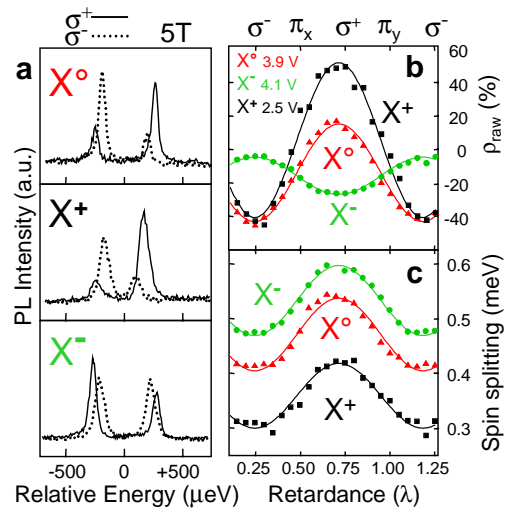


FIG. 3 (color online). (a) PL spectra of X^0 , X^- , and X^+ in a longitudinal magnetic field (5 T) for both polarizations of the laser. (b) Raw polarizations calculated from peak intensities in each Zeeman doublet, as a function of laser polarization. (c) Spin splitting (Zeeman splitting + Overhauser shift) as a function of laser polarization (retardance).

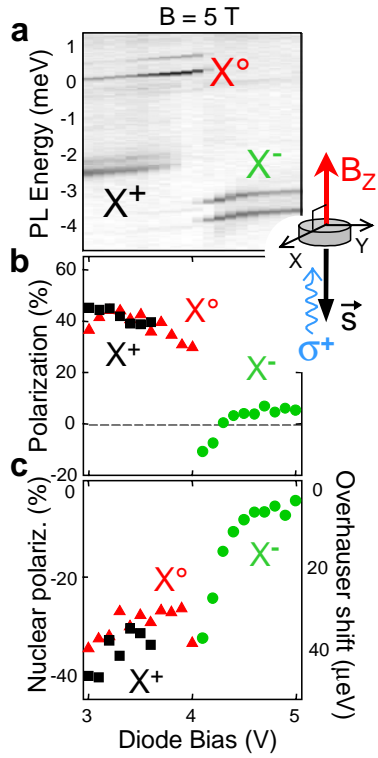


FIG. 4 (color online). (a) PL intensity (gray scale) for a single quantum dot as a function of the emitted photon energy and applied bias at 5 T and σ^- laser polarization. (b) Polarization memory calculated from peak intensities in (a) and in the analogous spectrum for σ^+ laser polarization. (c) Nuclear spin polarization (proportional to Overhauser shift) obtained from doublet splittings in (a) and in the analogous spectrum for σ^+ laser polarization.

polarization to the nuclear spins in the QD through a hyperfine flip-flop process [1,14]. Holes do not transfer their spins because they do not interact strongly with the nuclei. The nuclear polarization P_N exerts an effective magnetic field on the electron spin, producing an Overhauser shift in the doublet splittings [seen as the amplitudes of the curves in Fig. 3(c)]. The nuclear polarization tracks the electron polarization and can therefore be tuned with the applied bias [Fig. 4(c)]. When X^0 or X^+ is present in the QD, P_N is large and mostly independent of bias. For X^- , P_N starts out large at 4 V bias, where most electrons are optically polarized, but decreases with increasing bias as unpolarized electrons are injected. This coincides with the increase in PL polarization and the suppression of the Hanle depolarization. For the highest laser pumping intensities, we have observed shifts of 81 μeV , corresponding to a degree of nuclear polarization $P_N = 60\%$. These shifts in the electron spin splitting would require an external magnetic field of 14 T to achieve through the usual Zeeman interaction (with $g_e = 0.2$), and could be used to advantage as a way to suppress the

influence of nuclear spin fluctuations [28] or as a form of long-lived quantum memory [30].

By combining the classic techniques of optical orientation with those of single dot spectroscopy, we reveal a much higher level of detail than that possible with ensemble measurements. We have observed dramatic differences in polarization behavior as we changed the charge state of a single quantum dot from positive to neutral to negative, and we have demonstrated efficient optical pumping of electron and nuclear spin.

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